

ABSTRACT OF THE DISCLOSURE

The present invention has the feature that, in
a semiconductor laser apparatus having a negative
electrode and a positive electrode sandwiching an
5 active region (active region layer), and an optical
resonance chamber which is defined by a high-reflecting
mirror and an output mirror positioned at the both
end portions thereof, the positive electrode and
an oscillation optical axis which is the axis of
10 the optical resonance chamber are made so as to be
non-parallel.